# **EPC GaN Transistor Qualification Report EPC2034**



Chris Jakubiec, Director of Reliability, Efficient Power Conversion Corporation

This report summarizes the Product Qualification results for EPC part number EPC2034. The EPC2034 meets all required qualification requirements and is released for production.

#### Scope

The testing matrix in this qualification report covers the qualification of EPC2034 listed in the table below. EPC2034 has the same die size, packaging process and bump design as EPC2029, EPC2032, EPC2033.

A qualification by similarity matrix approach is applied, with the table of part numbers formed by associated die family (same die process and design rules) and package family (same package process and design rules). The intent of qualification by similarity is that all potential failure mechanisms for the part numbers in the table are included and represented by the samples of each individual test.

All part numbers in the table with samples that have not been included in each of the individual tests listed in this report, are considered qualified by similarity in accordance with the above defined die and package families.

Part Number	Voltage (V)	$R_{DS(on)} \ (m\Omega)$	Die Size (mm x mm)
EPC2032	100	4	XL (4.65 x 2.65)
EPC2029	80	3.2	XL (4.65 x 2.65)
EPC2001C	100	7	L (4.11 x 1.63)
EPC2016C	100	16	M (2.11 x 1.63)
EPC800x	40	250	S (2.05 x 0.85)
EPC2036	100	65	S (0.95 x 0.95)
EPC2035	60	45	S (0.95 x 0.95)
EPC2015C	60	45	L (4.11 x 1.63)
EPC2033	150	7	XL (4.65 x 2.65)
EPC2034	200	10	XL (4.65 x 2.65)
EPC2022	100	3.2	XL (6.10 x 2.35)
EPC2021	80	2.5	XL (6.10 x 2.35)
EPC2023	30	1.3	XL (6.10 x 2.35)

#### **Qualification Test Overview**

EPC's eGaN FETs were subjected to a wide variety of stress tests under conditions that are typical for silicon-based power MOSFETs. These tests included:

- High temperature reverse bias (HTRB): Parts are subjected to a drain-source voltage at the maximum rated temperature
- High temperature gate bias (HTGB): Parts are subjected to a gate-source voltage at the maximum rated temperature
- High temperature storage (HTS): Parts are subjected to heat at the maximum rated temperature
- Temperature cycling (TC): Parts are subjected to alternating high- and low temperature extremes
- High temperature high humidity reverse bias (H3TRB): Parts are subjected to humidity under high temperature with a drain-source voltage applied
- Unbiased autoclave (AC or Pressure Cooker Test): Parts are subjected to pressure, humidity, and temperature under condensing conditions
- Moisture sensitivity level (MSL): Parts are subjected to moisture, temperature, and three cycles of reflow.

The stability of the devices is verified with DC electrical tests after stress biasing. The electrical parameters are measured at time-zero and at interim readout points at room temperature. Electrical parameters such as the gate-source leakage, drain-source leakage, gate-source threshold voltage, and on-state resistance are compared against the data sheet specifications. A failure is recorded when a part exceeds the datasheet specifications. eGaN FETs are stressed to meet the latest Joint Electron Device Engineering Council (JEDEC) standards when possible.

Parts were mounted onto FR5 (high Tg FR4) or polyimide adaptor cards. Adaptor cards of 1.6 mm in thickness with two copper layers were used. The top copper layer was 1 oz. or 2 oz., and the bottom copper layer was 1 oz. Kester NXG1 type 3 SAC305 solder no clean flux was used in mounting the part onto an adaptor card.

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#### **High Temperature Reverse Bias**

Parts were subjected to 80% or 100% of the rated drain-source voltage at the maximum rated temperature for a stress period of 500 hours or 1000 hours.

Stress Test	Part Number	Voltage (V)	Die Size (mm x mm)	Test Condition	# of Failure	Sample Size (sample x lot)	Duration (Hrs)
HTRB	EPC2010C	200	L (3.55 x 1.63)	$T = 150$ °C, $V_{DS} = 160 \text{ V}$	0	77 x 2	1000
HTRB	EPC2012C	200	M (1.71 x 0.92)	$T = 150$ °C, $V_{DS} = 160 \text{ V}$	0	77 x 1	1000
HTRB	EPC2034	200	XL (4.65 x 2.65)	$T = 150$ °C, $V_{DS} = 160 \text{ V}$	0	77 x 1	1000

Table 1. High Temperature Reverse Bias Test

## **High Temperature Gate Bias**

Parts were subjected to 5.5 V or 5.75 V gate-source bias at the maximum rated temperature for a stress period of 500 hours or 1000 hours.

Stress Test	Part Number	Voltage (V)	Die Size (mm x mm)	Test Condition	# of Failure	Sample Size (sample x lot)	Duration (Hrs)
HTGB	EPC2010C	200	L (3.55 x 1.63)	$T = 150$ °C, $V_{GS} = 5.75$ V	0	77 x 2	1000
HTGB	EPC2012C	200	M (1.71 x 0.92)	$T = 150$ °C, $V_{GS} = 5.75$ V	0	77 x 1	1000
HTGB	EPC2034	200	XL (4.65 x 2.65)	$T = 150$ °C, $V_{GS} = 5.75$ V	0	77 x 1	1000

Table 2. High Temperature Gate Bias Test

#### **High Temperature Storage**

Parts were subjected to heat at the maximum rated temperature.

Stress Test	Part Number	Voltage (V)	Die Size (mm x mm)	Test Condition	# of Failure	Sample Size (sample x lot)	Duration (Hrs)
HTS	EPC2032	100	XL (4.65 x 2.65)	T = 150°C, Air	0	77 x 1	1000
HTS	EPC2029	80	XL (4.65 x 2.65)	T = 150°C, Air	0	25 x 3	1000
HTS	EPC2021	80	XL (6.10 x 2.35)	T = 150°C, Air	0	25 x 1 77 x 1	1000
HTS	EPC2022	100	XL (6.10 x 2.35)	T = 150°C, Air	0	77 x 1	1000
HTS	EPC2023	30	XL (6.10 x 2.35)	T = 150°C, Air	0	25 x 1	1000
HTS	EPC2001C	100	L (4.11 x 1.63)	T = 150°C, Air	0	77 x 1	1000
HTS	EPC2016C	100	M (2.11 x 1.63)	T = 150°C, Air	0	77 x 2	1000
HTS	EPC800x	40	S (2.05 x 0.85)	T = 150°C, Air	0	77 x 3	1000

Note - EPC2034 is qualified by matrix.

Table 3. High Temperature Storage Test

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#### **Temperature Cycling**

Parts were subjected to temperature cycling between -40°C and +125°C for a total of 1000 cycles. Ramp rate of 15°C/min and dwell time of 5 minutes were used in accordance with the JEDEC Standard JESD22A104.

Stress Test	Part Number	Voltage (V)	Die Size (mm x mm)	Test Condition	# of Failure	Sample Size (sample x lot)	Duration (Cys)
TC	EPC2029	80	XL (4.65 x 2.65)	−40 to +125°C, Air	0	35 x 2 77 x 1	1000
TC	EPC2032	100	XL (4.65 x 2.65)	−40 to +125°C, Air	0	77 x 2	1000
TC	EPC2001C	100	L (4.11 x 1.63)	−40 to +125°C, Air	0	35 x 3	1000
TC	EPC800x	40	S (2.05 x 0.85)	−40 to +125°C, Air	0	35 x 1 77 x 3	1000

**Note** - EPC2034 is qualified by matrix.

Table 4. Temperature Cycling Test

## **High Temperature High Humidity Reverse Bias**

Parts were subjected to a drain-source bias at 85% RH and 85°C for a stress period of 1000 hours. The testing was done in accordance with the JEDEC Standard JESD22A101.

Stress Test	Part Number	Voltage (V)	Die Size (mm x mm)	Test Condition	# of Failure	Sample Size (sample x lot)	Duration (Hrs)
H3TRB	EPC2032	100	XL (4.65 x 2.65)	$T = 85$ °C, RH = 85%, $V_{DS} = 80 \text{ V}$	0	25 x 1	1000
H3TRB	EPC2033	150	XL (4.65 x 2.65)	T = 85°C, RH = 85%, V <sub>DS</sub> = 100 V	0	25 x 2	1000
H3TRB	EPC2029	80	XL (4.65 x 2.65)	$T = 85$ °C, RH = 85%, $V_{DS} = 64 \text{ V}$	0	25 x 1	1000
H3TRB	EPC2022	100	XL (6.10 x 2.35)	T = 85°C, RH = 85%, V <sub>DS</sub> = 80 V	0	50 x 1 25 x 1	1000
H3TRB	EPC2023	30	XL (6.10 x 2.35)	$T = 85$ °C, RH = 85%, $V_{DS} = 24 \text{ V}$	0	77 x 1	1000
H3TRB	EPC2001C	100	L (4.11 x 1.63)	$T = 85$ °C, RH = 85%, $V_{DS} = 80 \text{ V}$	0	25 x 1	1000
H3TRB	EPC2016C	100	M (2.11 x 1.63)	$T = 85$ °C, RH = 85%, $V_{DS} = 80 \text{ V}$	0	25 x 2	1000

*Note* - EPC2034 is qualified by matrix.

Table 5. High Temperature High Humidity Reverse Bias Test

### **Moisture Sensitivity Level**

Parts were subjected to 85% RH at 85°C for a stress period of 168 hours. The parts were also subjected to three cycles of Pb-free reflow in accordance with the IPC/JEDEC joint Standard J-STD-020.

Stress Test	Part Number	Voltage (V)	Die Size (mm x mm)	Test Condition	# of Failure	Sample Size (sample x lot)	Duration (Hrs)
MSL1	EPC2032	100	XL (4.65 x 2.65)	T = 85°C, RH = 85%, 3 reflow	0	77 x 1	168
MSL1	EPC2029	80	XL (4.65 x 2.65)	T = 85°C, RH = 85%, 3 reflow	0	25 x 2 77 x 2	168
MSL1	EPC2001C	100	L (4.11 x 1.63)	T = 85°C, RH = 85%, 3 reflow	0	25 x 1	168
MSL1	EPC800x	40	S (2.05 x 0.85)	T = 85°C, RH = 85%, 3 reflow	0	77 x 3	168

Note - EPC2034 is qualified by matrix.

Table 6. Moisture Sensitivity Level Test